

SDB2045P

Schottky Barrier Rectifier

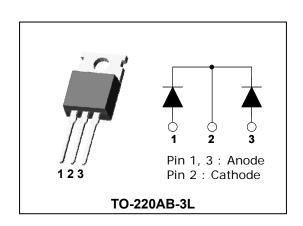
LOW VOLTAGE SCHOTTKY RECTIFIER

Features

- Low forward voltage drop and leakage current
- Low power loss and High efficiency
- Guard-ring for overvoltage protection
- · Dual common cathode rectifier
- Full lead (Pb)-free and RoHS compliant device

Applications

- Power supply Output rectification
- High efficiency SMPS
- Free-wheeling diode
- Reverse battery protection
- · DC to DC systems



Product Characteristics

I _{F(AV)}	2 X 10A
V_{RRM}	45V
V _{FM} at 125℃	0.50V
I _{FSM}	120A

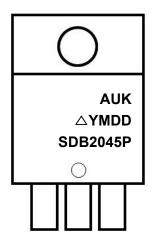
Description

Schottky barrier rectifier designed for high frequency miniature Switched Mode Power Supplies such as adaptors and on board DC to DC converters.

Ordering Information

Device Marking Code		Package	Packaging	
SDB2045P	SDB2045P	TO-220AB-3L	Tube	

Marking Information



AUK = Manufacture Logo

 Δ = Control Code of Manufacture

YMDD = Date Code Marking

-. Y = Year Code

-. M = Monthly Code

-. DD = Daily Code

SDB2045P = Specific Device Code

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Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit	
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V _{RRM} V _{RWM} V _R	45	٧	
Maximum average forward rectified current	per diode	1	10		
Maximum average forward rectified current	total device	I _{F(AV)}	20	A	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I _{FSM}	120	А	
Storage temperature range Maximum operating junction temperature		T _{stg}	-45 to +150		
		TJ	150	\mathbb{C}	

Thermal Characteristics

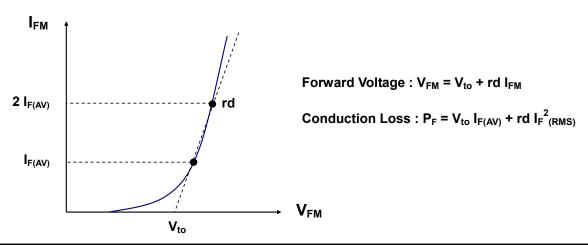
Characteristic		Symbol	Value	Unit
Maximum thermal resistance junction to case	per diode	D	3.0	- ℃/W
	total device	$R_{th(j-c)}$	2.8	

Electrical Characteristics (Per Diode)

Characteristic	Symbol	Test Condition		Min.	Тур.	Max.	Unit
Peak forward voltage drop	V _{FM} ⁽¹⁾	I _{FM} = 10A	T _j =25 ℃	1	1	0.54	V
			T _j =125℃		-	0.50	
Reverse leakage current	I _{RM} ⁽¹⁾	$V_R = V_{RRM}$	T _j =25 ℃	-	-	1.5	Λ
			T _j =125℃	-	-	150	- mA
Junction capacitance	C _j	$V_R = 5V_{DC}$, $f=1MHz$		-	550	-	pF

Note : (1) Pulse test : $t_P \le 380us$, Duty cycle $\le 2\%$

To evaluate the conduction losses use the following equation (Fig 4.) : $P_F = 0.35 \text{ x } I_{F(AV)} + 0.015 I_F^2_{(RMS)}$



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Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics (Per diode)

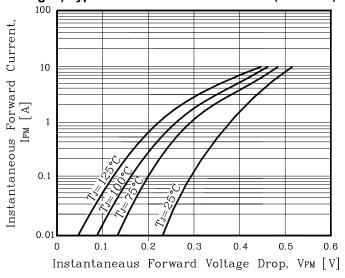


Fig. 2) Typical Reverse Characteristics (Per diode)

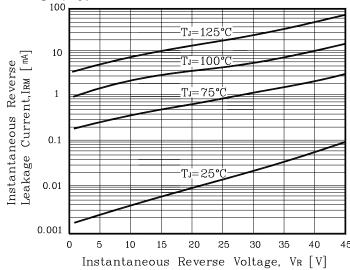


Fig. 3) Maximum Forward Derative Curve

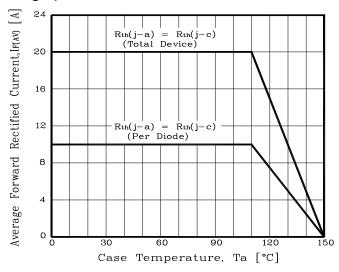


Fig. 4) Forward Power Dissipation (Per diode)

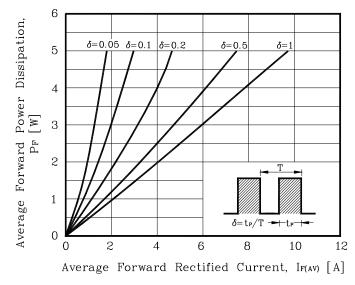


Fig. 5) Maximum Non-Repetitive Peak Forward Surge Current (Per diode)

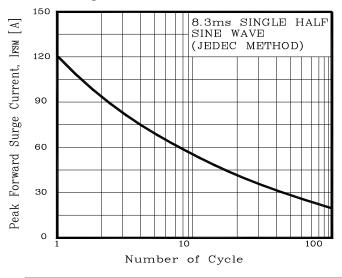
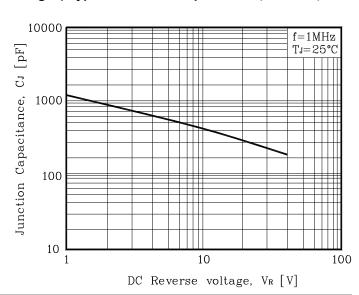


Fig. 6) Typical Junction Capacitance (Per diode)

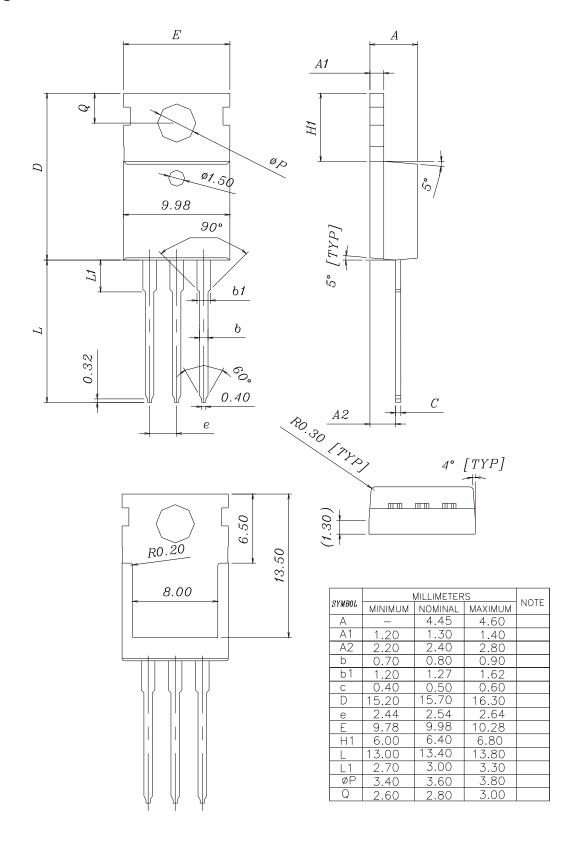


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Package Outline Dimension



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